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# Enhanced interfacial charge transport motivated by $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$ heterointerface for superior $\text{Zn}^{2+}$ and $\text{NH}_4^+$ storage system

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Aqueous energy storage technologies hold great promise in the renewable energy field. Transition metal dichalcogenides (TMDs) have garnered significant attention as prospective cathode materials. However, their development has been hampered by sluggish ionic transport kinetics and structural instability during repeated ion insertion/extraction processes. Herein, a heterostructured  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  composite anchored on nitrogen-doped carbon frameworks ( $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$ ) is designed to address these challenges. The formation of a built-in electric field at the heterojunction interface, in conjunction with the conductive NC framework, promotes uniform material distribution and effectively mitigates volume expansion during  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  intercalation/de-intercalation. Density functional theory (DFT) calculations reveal that the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  heterointerface exhibits enhanced adsorption energies for both  $\text{Zn}^{2+}$  (−1.687 eV) and  $\text{NH}_4^+$  (−2.296 eV) compared to pristine  $\text{Bi}_2\text{Te}_3$ . These synergistic effects collectively contribute to outstanding dual-ion storage capabilities, as evidenced by the high specific capacity of  $295 \text{ mA h g}^{-1}$  at  $1 \text{ A g}^{-1}$  for zinc-ion storage and  $325 \text{ mA h g}^{-1}$  at  $0.5 \text{ A g}^{-1}$  for ammonium-ion storage. Remarkably, the hybrid device achieves exceptional long-term cycling stability with 99.1% capacity retention after 9000 cycles for  $\text{Zn}^{2+}$  and 84.66% retention after 2000 cycles for  $\text{NH}_4^+$ . This work provides fundamental insights into heterointerface engineering for developing high-performance dual-ion battery systems.

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## Introduction

The depletion of traditional fossil fuels, climate warming, and environmental pollution have driven the development of renewable energy technologies. Aqueous energy batteries have emerged as an attractive candidate due to their eco-friendliness, intrinsic safety and ultrafast charge/discharge capability.<sup>1–7</sup> Among various systems, dual-ion batteries represent a promising direction due to their ability to utilize multiple charge carriers (e.g.,  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$ ). However, such systems face challenges including sluggish reaction kinetics and poor

structural stability under the intercalation of different ionic species.

Transition metal dichalcogenides (TMDs), such as bismuth telluride ( $\text{Bi}_2\text{Te}_3$ ), have been widely investigated as cathode candidates for aqueous rechargeable batteries due to their layered structures and tunable electrochemical properties.<sup>8–11</sup> While their widespread application is constrained by sluggish ion diffusion kinetics and structural instability during repeated charge–discharge cycles, primarily attributable to intrinsic lattice limitations and interfacial instability.<sup>12–15</sup> Although heterojunction engineering has demonstrated potential in optimizing charge transfer dynamics,<sup>16,17</sup> the rational design of heterointerfaces with balanced lattice compatibility and robust built-in electric fields remains a significant challenge, particularly in dual-ion storage systems involving diverse charge carriers.

Recent advances highlight the pivotal role of interface modulation in enhancing battery performance.<sup>18,19</sup> Heterostructures with work function differences can create spontaneous interfacial electric fields, while lattice matching at phase boundaries alleviates mechanical strain during ion intercalation.<sup>20,21</sup> Nevertheless, current strategies often neglect the synergistic requirements of dual-ion coordination chemistry and long-term structural durability. To address these

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limitations, we introduce a heterojunction engineering strategy *via* the integration of bismuth telluride ( $\text{Bi}_2\text{Te}_3$ ) and antimony phosphate ( $\text{SbPO}_4$ ) anchored on nitrogen-doped carbon frameworks ( $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$ ). This architecture leverages the complementary attributes of the constituent phases.  $\text{Bi}_2\text{Te}_3$  provides a stable conductive matrix, while  $\text{SbPO}_4$  serves as a structural stabilizer and interface modifier. Its lattice compatibility with  $\text{Bi}_2\text{Te}_3$  not only creates a strong built-in electric field but also provides a coherent and durable mechanical support to buffer the volume change of  $\text{Bi}_2\text{Te}_3$ .<sup>22–24</sup> The nitrogen-doped carbon substrate further enhances electron transport and mitigates volume fluctuations.<sup>25,26</sup>

Theoretical calculations and experimental assessments confirm that the designed heterointerface establishes an efficient charge redistribution network. The work function difference between  $\text{Bi}_2\text{Te}_3$  and  $\text{SbPO}_4$  induces a strong built-in electric field, significantly lowering the energy barriers for  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  migration. Simultaneously, their lattice coherence minimizes interfacial strain, preserving structural integrity during repetitive ion insertion/extraction. Moreover, the hybrid configuration demonstrates exceptional dual-ion storage performance, including high reversible capacities of  $295 \text{ mA h g}^{-1}$  at  $1 \text{ A g}^{-1}$  for  $\text{Zn}^{2+}$  and  $325 \text{ mA h g}^{-1}$  at  $0.5 \text{ A g}^{-1}$  for  $\text{NH}_4^+$ , along with exceptional long-term cycling stability (99.1% retention after 9000 cycles for  $\text{Zn}^{2+}$  and 84.66% after 2000 cycles for  $\text{NH}_4^+$ ). Furthermore, a hybrid-ion battery assembled in a  $15 \text{ M CH}_3\text{COONH}_4 + 2 \text{ M ZnSO}_4$  aqueous electrolyte maintains 78.27% capacity retention over 8000 cycles under a high current density of  $5 \text{ A g}^{-1}$ . This work provides fundamental insights into heterointerface design for high-energy-density, long-lifespan dual-ion storage devices.

## Results and discussion

The role of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  heterointerface in charge transfer and ion storage processes was studied by the first-principles calculations based on density functional theory (DFT). Fig. 1a–c present the optimized crystal structure models of  $\text{Bi}_2\text{Te}_3$ ,  $\text{SbPO}_4$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$ , respectively. Compared with pure  $\text{Bi}_2\text{Te}_3$  material,  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  exhibits enhanced electrical conductivity, with the interface offering abundant active sites and efficient pathway for  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  transport (Fig. 1d). The charge density difference analysis reveals a significant charge redistribution at the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  heterojunction interface, indicating pronounced electron transfer from  $\text{SbPO}_4$  to  $\text{Bi}_2\text{Te}_3$  (Fig. 1e–h). Yellow and blue regions represent charge accumulation and depletion, respectively. Furthermore, the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  system demonstrates higher adsorption energies for  $\text{Zn}^{2+}$  ( $-1.687 \text{ eV}$ ) and  $\text{NH}_4^+$  ( $-2.296 \text{ eV}$ ) compared to the pure  $\text{Bi}_2\text{Te}_3$  model, suggesting that the heterointerface is more conducive to the storage of  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$ .

Fig. 2a shows the synthesis process of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  nanorods. Detailed synthesis information is provided in the Experimental Section. The phase composition and crystalline structure of the samples were characterized by X-ray diffraction (XRD). As shown in Fig. 2b and S1, the diffraction peaks of the composite match well with  $\text{Bi}_2\text{Te}_3$  (PDF#15-0863) and  $\text{SbPO}_4$

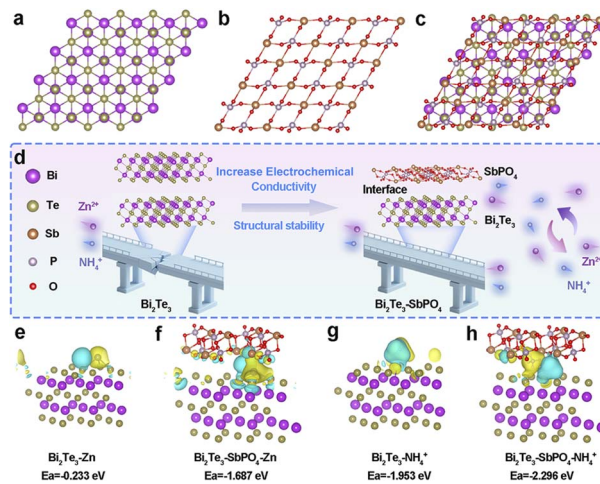


Fig. 1 Theoretical simulation models of (a)  $\text{Bi}_2\text{Te}_3$ , (b)  $\text{SbPO}_4$  and (c)  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$ . Schematic illustration of the optimization strategies of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  electrode and (d) the feasibility analyses of  $\text{NH}_4^+/\text{Zn}^{2+}$  co-storage chemistry in  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$ .  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  adsorption energy of the proposed configurations, yellow and blue regions represent the charge accumulation and the charge depletion (e–h).

(PDF#71-2275), confirming the successful construction of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  heterojunction. X-ray photoelectron spectroscopy (XPS) verified the presence of Bi, Te, Sb, P, O and C elements in the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  sample (Fig. S2). In the high-resolution Bi 4f spectrum (Fig. 2c), the peaks at  $159.4 \text{ eV}$  and  $164.7 \text{ eV}$  are assigned to Bi 4f<sub>7/2</sub> and Bi 4f<sub>5/2</sub>, respectively. In the Te 3d spectrum (Fig. 2d), two distinct peaks at  $572.2 \text{ eV}$

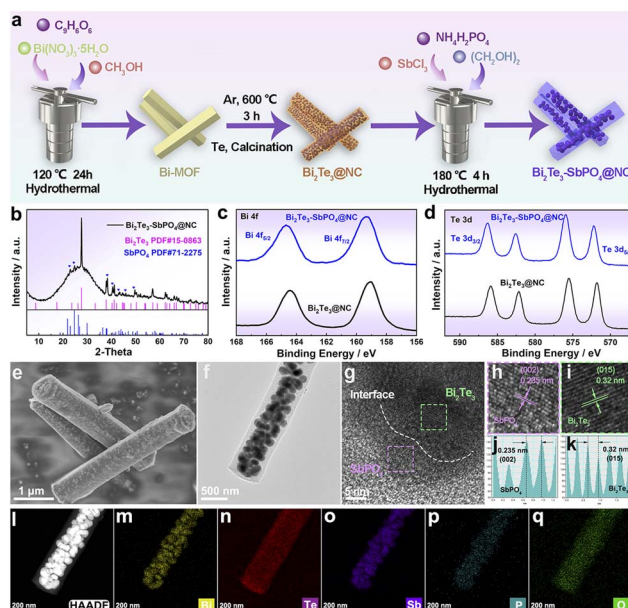


Fig. 2 (a) Schematic of the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  heterojunction fabrication process. (b) XRD pattern. XPS spectra of (c) Bi 4f, (d) Te 3d. (e) SEM image of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$ . (f) TEM image of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$ . (g–i) HRTEM image. (j and k) Lattice distance. (l) The HAADF image of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  and (m–q) the corresponding element mappings.



(Te 3d5/2) and 586.3 eV (Te 3d3/2) correspond to Te–Bi and Te–O bonding environments.<sup>27</sup> Notably, in both the Bi 4f and Te 3d spectra, the binding energies exhibit a positive shift in the heterojunction material, which can be attributed to the difference in work function between Bi<sub>2</sub>Te<sub>3</sub> and SbPO<sub>4</sub> (Fig. S3). This drives electron transfer from Bi<sub>2</sub>Te<sub>3</sub> to SbPO<sub>4</sub>, resulting in the formation of a built-in electric field. Additionally, the presence of Sb, P, O signals in the heterojunction (Fig. S4) further confirms the successful incorporation of SbPO<sub>4</sub>.<sup>28</sup> Morphological and internal structure of the prepared materials were characterized by field emission scanning electron microscopy (SEM) and transmission electron microscopy (TEM). The Bi-BTC precursor exhibits uniform nanorod morphology (Fig. S5), and the resulting Bi<sub>2</sub>Te<sub>3</sub>@NC maintains the one-dimensional structure well after tellurization process (Figure S6-7). In contrast to pristine Bi<sub>2</sub>Te<sub>3</sub>@NC, the heterojunction material displays porous nanorods with larger particles encapsulated within a carbon shell (Fig. 2e and f). The porous architecture effectively mitigates mechanical fracture during ions insertion/ (de)insertion processes, thereby facilitating ion transport (Fig. S8). The high-resolution TEM (HRTEM) images (Fig. 2g–k) reveal the interplanar spacings of 0.32 nm and 0.235 nm, corresponding to the (015) plane of Bi<sub>2</sub>Te<sub>3</sub> and the (002) plane of SbPO<sub>4</sub>, respectively. The selected area electron diffraction (SAED) pattern in Fig. S9 confirms the polycrystalline nature of the material. Furthermore, the high-angle annular dark-field (HAADF) image and corresponding energy dispersive spectrometer (EDS) elemental mappings demonstrate the uniform distribution of Bi, Te, Sb, P and O elements (Fig. 2l–q). These results confirm the successful synthesis of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC heterojunction nanorods. Compared to Bi<sub>2</sub>Te<sub>3</sub>@NC, heterojunction materials enhances ion adsorption and effectively accommodates volume changes during repeated charge–discharge cycles. Since SbPO<sub>4</sub> is electrochemically inert (Fig. S10), we only compare the electrochemical performance of Bi<sub>2</sub>Te<sub>3</sub>@NC and Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC in the following.

The electrochemical properties of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC and pristine Bi<sub>2</sub>Te<sub>3</sub>@NC electrode were systematically studied in 2 M ZnSO<sub>4</sub> electrolyte. The cyclic voltammetry (CV) curve of the heterojunction exhibits minimal variation compared to those of Bi<sub>2</sub>Te<sub>3</sub>@NC (Fig. 3a and S11), retaining a pair of well-defined and reversible redox peaks, indicating similar redox behavior. Fig. 3b shows the galvanostatic charge–discharge (GCD) profiles of the heterojunction at various current densities. Reversible capacities of 330, 318, 295, 280, 259 mA h g<sup>−1</sup> are achieved at current densities of 0.5, 0.8, 1, 3, 5 A g<sup>−1</sup>, respectively (Fig. 3c). When the current density is restored to 0.5 A g<sup>−1</sup>, the electrode recovers its capacity, exhibiting excellent rate capability (Fig. S12). To further evaluate and compare the electrochemical performance, key parameters including coulombic efficiency (CE), capacity retention, and specific capacity are plotted in a visual radar chart (Fig. 3d). The Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC heterojunction outperforms previously reported transition metal compounds in zinc ion storage performance.<sup>29–34</sup> The long-term electrochemical stability was assessed, the Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC delivers an initial capacity of 300 mA h g<sup>−1</sup> at 0.5 A g<sup>−1</sup> and maintains the capacity over 100 cycles, exhibiting superior

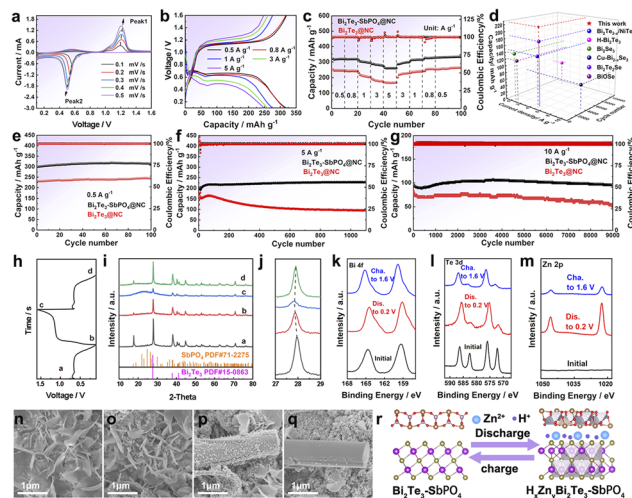


Fig. 3 The electrochemical properties of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC: (a) CV curves from 0.1 to 1.6 V at 0.1–0.5 mV s<sup>−1</sup>. (b) The GCD curves under 0.5–5 A g<sup>−1</sup>. (c) Rate performance of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC and Bi<sub>2</sub>Te<sub>3</sub>@NC. (d) Capacity comparison of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC with state-of-the-art Zn<sup>2+</sup> storage cathode. (e–g) Cycling performance of Bi<sub>2</sub>Te<sub>3</sub>@NC and Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC. (h–j) *Ex situ* XRD result obtained from the heterojunction cathodes at different states. (k) Bi 4f, (l) Te 3d, (m) Zn 2p XPS obtained from the Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC heterojunction cathodes. SEM images of (n–o) Bi<sub>2</sub>Te<sub>3</sub>@NC and (p and q) Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC at the fully discharged–charged states, respectively. (r) Schematic diagram presents the charge storage mechanism in the heterojunction cathode.

cycling stability relative to pristine Bi<sub>2</sub>Te<sub>3</sub>@NC (Fig. 3e). Even under high current densities of 5 A g<sup>−1</sup> for 1100 cycles (Fig. 3f) and 10 A g<sup>−1</sup> for 9000 cycles (Fig. 3g), the heterojunction demonstrates significantly enhanced capacity retention and exceptional cycle durability. These results underscore the outstanding rate capability and remarkable structural stability of the Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC heterojunction. The outstanding electrochemical performance of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC heterojunction primarily is attributed to the strong built-in electric field at the interface of Bi<sub>2</sub>Te<sub>3</sub> and SbPO<sub>4</sub>, which effectively promotes charge transfer and mitigates volume expansion during cycling. The reaction kinetics of the samples were investigated in Fig. S13. To fully elucidate the energy storage mechanism of Bi<sub>2</sub>Te<sub>3</sub>–SbPO<sub>4</sub>@NC, the phase evolution during the charge–discharge process was analyzed by *ex-situ* XRD, XPS and SEM. GCD test was conducted at 0.8 A g<sup>−1</sup> (Fig. 3h). The XRD pattern in Fig. 3i clearly shows the characteristic peaks of Bi<sub>2</sub>Te<sub>3</sub> (PDF#15-0863) and SbPO<sub>4</sub> (PDF#71-2275), with no additional diffraction peaks observed throughout the cycling process. It is worth noting that at 2θ = 27.8°, the (015) crystal plane of Bi<sub>2</sub>Te<sub>3</sub> gradually moves to a lower angle upon discharge to 0.1 V (Fig. 3j), and reverts to its original position when charge to 1.6 V, indicating the reversible Zn<sup>2+</sup>/H<sup>+</sup> insertion/extraction. XPS analysis provides further insights into electrochemical behavior. The Bi 4f spectrum shows negligible changes in the Bi–O and Bi–Te bonding environments during the redox process (Fig. 3k). In the Te XPS profile, the Te–Te bond disappears during cycling, while the Te–O and Te–Bi peaks remain



largely unchanged (Fig. 3l), further highlighting the structural stability of the heterojunction. In the Zn 2p XPS spectrum (Fig. 3m), two obvious Zn signals are detected at 1022.58 eV and 1045.6 eV in the fully discharged state, and these signals are weaker significantly in the fully charged state, confirming the reversible insertion/de-insertion of  $\text{Zn}^{2+}$ . To verify the  $\text{H}^+$  intercalation, CV curves were compared in  $\text{ZnSO}_4/\text{DMSO}$  and  $\text{ZnSO}_4/\text{H}_2\text{O}$  electrolytes, respectively (Fig. S14 and 15). The higher CV area observed in the  $\text{ZnSO}_4/\text{H}_2\text{O}$  electrolyte compared to that in  $\text{ZnSO}_4/\text{DMSO}$  electrolyte suggests a synergistic  $\text{Zn}^{2+}/\text{H}^+$  co-insertion mechanism.<sup>35,36</sup> The morphological evolution of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  and  $\text{Bi}_2\text{Te}_3@\text{NC}$  was examined by SEM. In the discharge state, obvious  $\text{Zn}_4\text{SO}_4(\text{OH})_6 \cdot x\text{H}_2\text{O}$  (ZSH) nanoflakes are observed on both electrodes (Fig. 3n and p). However, in the fully charged state, residual ZSH deposits persist on  $\text{Bi}_2\text{Te}_3@\text{NC}$ , whereas they are nearly absent on  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  (Fig. 3o and q), indicating enhanced reaction reversibility in the heterojunction. Based on the above studies, a schematic illustration summarizing the structural evolution during electrochemical intercalation is proposed to depict the  $\text{Zn}^{2+}/\text{H}^+$  storage behavior within the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  heterojunction host (Fig. 3r).<sup>37</sup>

The  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  material exhibits excellent electrochemical performance in ZIBs, prompting further investigation into its behavior in ammonium-ion batteries (AIBs). We tested the electrochemical performance of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  heterojunction materials in 1 M and 5 M  $\text{CH}_3\text{COONH}_4$  as electrolytes (Fig. S16). It can be found that the electrochemical performance increases with the increase of concentration. In the 15 M  $\text{CH}_3\text{COONH}_4$  as electrolyte, it shows better electrochemical performance. This is due to the fact that acetate ions are involved in the formation of solvated  $\text{NH}_4^+$  in high concentration electrolyte, which promotes the adsorption of solvated  $\text{NH}_4^+$  clusters on the electrode surface.<sup>38</sup> The electrochemical properties of  $\text{Bi}_2\text{Te}_3$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  were studied by using 15 M

$\text{CH}_3\text{COONH}_4$  as electrolyte. From Fig. 4a–b, the heterojunction electrode displays stronger CV redox peak and more obvious charge–discharge platform, indicating enhanced  $\text{NH}_4^+$  storage capability. The CV and GCD curves of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  and  $\text{Bi}_2\text{Te}_3@\text{NC}$  are shown in Fig. 4c, d and S17, respectively. In impedance test (Fig. 4e), the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  delivers a lower charge transfer resistance, delivering the enhanced charge transport efficiency. Rate capability of the samples was also evaluated (Fig. 4f). The  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  electrode exhibits superior rate performance and reversibility with a recoverable capacity of  $350 \text{ mA h g}^{-1}$ . The  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  can maintain a high capacity retention of 84.66% when cycled for 2000 times at  $3 \text{ A g}^{-1}$  (Fig. 4g). The energy storage kinetics of the sample in 15 M  $\text{CH}_3\text{COONH}_4$  is evaluated (Fig. S18 and 19).

To explore the  $\text{NH}_4^+$  storage mechanism in  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$ , *ex-situ* XRD and XPS tests were carried out. The charge–discharge test was conducted at  $0.5 \text{ A g}^{-1}$  (Fig. 4h). XRD test revealed no formation of new phase after fully charge–discharge process (Fig. 4i). By enlarging the XRD spectrum near  $27.8^\circ$ , it can be observed that the peak moves to a low angle during the discharge process, which is attributed to the insertion process of  $\text{NH}_4^+$ . During the subsequent charge process, the peak returns to a high angle, corresponding to the extraction of  $\text{NH}_4^+$  (Fig. 4j). The chemical states of Bi, Te, N, and O in charge–discharge state were studied by *ex-situ* XPS spectroscopy (Fig. 4k and S20). In the three-dimensional XPS spectra of Bi 4f and Te 3d, it can be found that the Bi–Te peak moves to the direction of high binding energy during charging, and then does not return to the initial state during discharging, indicating that there is a certain degree of irreversible reaction. In the N 1s spectrum (Fig. 4l), a strong  $-\text{N}-\text{H}-$  peak appears in the fully discharged state, which proves the insertion of  $\text{NH}_4^+$ . However, upon fitting and integration of the N 1s spectra, the charged state shows no significant extra area compared to the pristine material, indicating that the N signal mainly comes from the NC framework itself rather than from residual  $\text{NH}_4^+$ . Therefore, the insertion and extraction of  $\text{NH}_4^+$  are essentially reversible. In the O 1s signal (Fig. S21), the enhancement of the O–H bond in the fully discharged state illustrated that the coinsertion of  $\text{H}^+$  was accompanied by the embedding of  $\text{NH}_4^+$ . The above results prove the reaction mechanism of  $\text{NH}_4^+$  insertion/extraction in  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$ .

Fig. 5a shows the electron flow mechanism at the heterogeneous interface within the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  heterojunction during the charge and discharge process. During charging, electrons transfer from  $\text{Bi}_2\text{Te}_3$  to  $\text{SbPO}_4$ , while during discharging, the direction reverses with electrons moving from  $\text{SbPO}_4$  back to  $\text{Bi}_2\text{Te}_3$ . The electronic properties of both  $\text{Bi}_2\text{Te}_3$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  were investigated using density functional theory (DFT) calculations. The computed band structures and partial density of states (PDOS) are presented in Fig. 5b and c. Obviously, the pristine  $\text{Bi}_2\text{Te}_3$  exhibits typical semiconductor behavior with a band gap of 0.95 eV. In contrast, the  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$  heterostructure displays additional occupied states near the Fermi level, indicating that interface coupling enhances the local electron concentration and improves electronic conductivity. Subsequently, the electrochemistry performance of

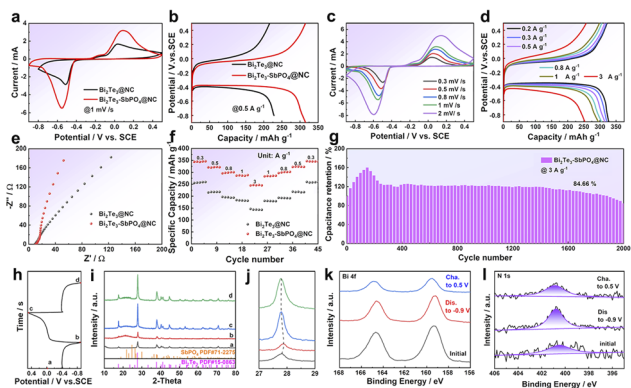


Fig. 4 Comparison of the electrochemical performance of  $\text{Bi}_2\text{Te}_3$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  electrodes in 15 M  $\text{CH}_3\text{COONH}_4$ : (a) CV curve at  $1 \text{ mV s}^{-1}$ ; (b) GCD curve at  $0.5 \text{ A g}^{-1}$ ; The electrochemical properties of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$ : (c) CV curves, (d) GCD curve. (e) EIS spectra. (f) The rate performance of  $\text{Bi}_2\text{Te}_3$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  electrodes. (g) The cycling performance of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$  electrode at  $3 \text{ A g}^{-1}$ . (h) GCD curve. (i and j) *Ex-situ* XRD patterns, (k) Bi 4f XPS spectra, and (l) N 1s XPS spectra of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4@\text{NC}$ .



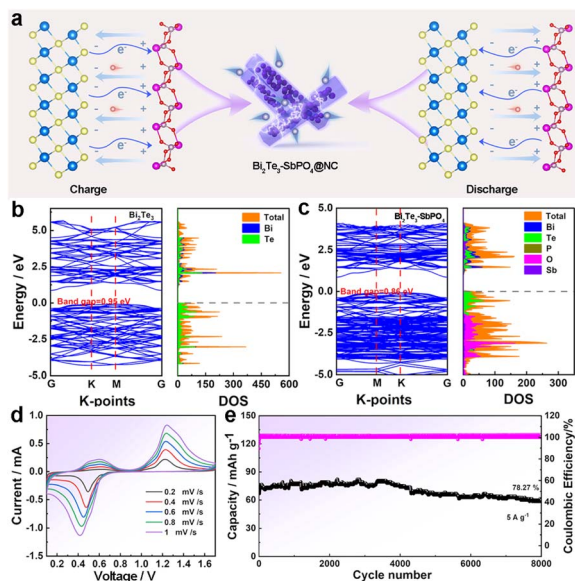


Fig. 5 (a) During the charge and discharge process, the electrons flow at the heterogeneous interface. (b and c) Energy band structure and density of state (DOS) of  $\text{Bi}_2\text{Te}_3$  and  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4$ . (d) CV curves of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  at 15 M  $\text{CH}_3\text{COONH}_4$  + 2 M  $\text{ZnSO}_4$  hybrid-ion electrolyte. (e) The cycling performance of  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  electrode at  $5 \text{ A g}^{-1}$ .

$\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  was evaluated in a 15 M  $\text{CH}_3\text{COONH}_4$  + 2 M  $\text{ZnSO}_4$  aqueous electrolyte by assembling coin cells. As shown in the CV curves (Fig. 5d), the heterojunction electrode exhibits well-defined redox peak. Even at a high current density of  $5 \text{ A g}^{-1}$ ,  $\text{Bi}_2\text{Te}_3\text{-SbPO}_4\text{@NC}$  achieves a capacity retention of 78.27% after 8000 cycles (Fig. 5e), with negligible changes in the GCD profiles (Fig. S22), showing exceptional cycling stability. This work demonstrates the feasibility of designing a bi-functional electrode for  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  storage.

## Conclusions

In summary, theoretical calculation and experimental validation demonstrate that the designed heterogeneous interface establishes an efficient charge redistribution network. The work function difference between  $\text{Bi}_2\text{Te}_3$  and  $\text{SbPO}_4$  induces a strong built-in electric field, which significantly lowers the energy barrier of  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  insertion. Concurrently, their lattice coherence minimizes the interfacial strain, thereby preserving structural integrity during repeated ion insertion/extraction processes. As a result, the electrode delivers a high specific capacity of  $295 \text{ mA h g}^{-1}$  ( $1 \text{ A g}^{-1}$ ) in  $\text{Zn}^{2+}$  storage and  $325 \text{ mA h g}^{-1}$  ( $0.5 \text{ A g}^{-1}$ ) in  $\text{NH}_4^+$  storage. Moreover, the hybrid structure maintains 99.1% of its capacity after 9000 cycles for  $\text{Zn}^{2+}$  storage and 84.66% capacity after 2000 cycles for  $\text{NH}_4^+$  storage. Furthermore, a hybrid-ion battery was assembled in a 15 M  $\text{CH}_3\text{COONH}_4$  + 2 M  $\text{ZnSO}_4$  aqueous electrolyte. Under a high current density of  $5 \text{ A g}^{-1}$ , the material maintains 78.27% capacity retention over 8000 cycles. This work demonstrates the

feasibility of designing a bi-functional electrode for  $\text{Zn}^{2+}$  and  $\text{NH}_4^+$  storage.

## Author contributions

Zhiyuan Zha: data curation, investigation, methodology, writing – original draft. Ruinan Chen: data curation, investigation. Tong Zhou: software. Daohong Zhang: supervision, funding. Qiufan Wang: writing – review & editing.

## Conflicts of interest

There are no conflicts to declare.

## Data availability

The data that support the findings of this study are available on request from the corresponding author, upon reasonable request.

Supplementary information: experimental details, XRD, SEM and TEM images, XPS, and electrochemical performance. See DOI: <https://doi.org/10.1039/d6sc02844f>.

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